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Injection of a single e<sup>-</sup> bunch (1nC; 16.7 mA), which collides at each turn with laser pulses at the IP, inside the FP optical resonator  $\rightarrow$  Hard X rays (45-90 keV), average flux (10<sup>11</sup>-10<sup>13</sup> ph/s) from Compton Back Scattering.



**RF Control System for ThomX Storage Ring** 

## 500 MHz Solid State Power Amplifier (SSPA)

SSPA using 6th generation LDMOS (BLF578) technology : based on 560 W CW amplifier modules 🗲 96 amplifier modules are mounted on 6 dissipaters



560 W CW- 500 MHz amplifier module (G = 16.2 dB, η = 60 %)



Eaton APR48-Energy Saver 220 V AC / 50 V DC power converters (High efficiency: 96%)



February 2015: SSPA assembling

March 2015: First tests on dummy load up to 52kW CW √



Single cell copper cavity of the ELETTRA type, with 2 tapers made of 316L stainless steel

Required voltage,  $V_{RF} = 500 \text{ kV} \rightarrow P_{RF} \approx 50 \text{ kW}$ HOM fequency tuning  $\rightarrow$  Prevent resonant excitation by the beam

- Cavity temperature control : 30 to 70°C (stability of ± 0,05°C)
- Movable HOM frequency shifter plunger (HOMFS)
- Axial deformation :  $\Delta L_{cav} \rightarrow \Delta f_o$  (~ 155 kHz/mm fundamental mode)

500 MHz RF Cavity





Two of the ESRF cavity cooling racks.

HOM impedance and instability thresholds

- $\Delta U_{rad} \sim 0 \rightarrow \tau_{damping} (\sim 1 \text{ s}) >> \tau_{storage} (\sim 20 \text{ ms})$

- - Cures to HOM impedances
  - « HOM de-Qing »  $\rightarrow$  limited to a few 10<sup>2</sup> over a wide frequency range
  - « HOM frequency tuning » more efficient for a small machine like ThomX :
  - Beam spectral line spacing,  $\delta f = 16.7 \text{ MHz} >> BW_{HOM} \sim a \text{ few } 10 \text{ KHz}$
  - HOM effective impedance, seen by the beam :  $R_{eff} \approx R_s / (2Q_0 \cdot \delta f / f_{HOM})^2 << R_s$

Although the modes which propagate into the tapers are less critical than the trapped modes, their impedances are still above the specified thresholds

→ Longitudinal & Transverse Feedbacks are required to bring additional damping

## Low Level RF & Feedback Systems





 $\checkmark$ 

TFB Rack based on **FPGA** processing



Damped in 20 µs

April 2015: All measurements achieved (pulse & CW, with full reflection and VSWR of 2.5:1)

→ Eff (DC)= 57% Eff (AC) = 54.7%

To preserve the beam quality  $\rightarrow$  Instability growth time ,  $\tau_i > 20 \text{ ms}$ 

 $\rightarrow$  Impedance thresholds : ~ 5 k $\Omega$ /m for dipole and 0.5 k $\Omega$ .GHz for monopole modes

→ In both, longitudinal & transverse cases, damping of Z<sub>HOM</sub> by few 10<sup>3</sup> is required !!



MO 500 MH ( $BW_{cav} = 25 \text{ kHz} \ll f_s$  $f_{e} = 400 \text{ kHz}$ Damping of the energy and phase oscillations with the LFB ( $\Delta \phi_{inj}$ =10°, G<sub>0</sub>=50, G<sub> $\phi$ </sub>=5,  $\delta$ =150ns) Fast perturbations @ fs  $\rightarrow \delta Ei$ ,  $\delta \Phi i$  errors at inj., HOM... LFB = Fast Beam Phase Loop + RF FB → τ damping ( ~ 20 µs )  $\begin{array}{l} \textbf{RF FB} \rightarrow \textbf{BW}_{eff} = \textbf{BW}_{cav} \text{ x } (1 + \textbf{G}_{o}) > \textbf{f}_{s} \rightarrow \textbf{Modulate } \textbf{V}_{cav} \text{ at } \textbf{f} > \textbf{f}_{s} \\ \textbf{(d}_{ampli-cav} \sim 10 \text{ m} \rightarrow \delta = 150 \text{ ns} \rightarrow \textbf{G}_{o} \sim 50 \rightarrow \textbf{BW}_{eff} > 1 \text{ MHz} >> \textbf{f}_{s} \end{array}$ **Phase loop**  $\int$  - Phase comparison between V<sub>MO</sub> & I<sub>b</sub> (BPM)  $(BW > f_s)$  $\int$  - The error signal, d $\varphi$  (+ 90°) controls a PS Conclusion



## Comp.

•  $V_{cav}(A, \phi)$  cst  $\ll \delta T$ ,  $\delta p$ , Power supply ripple @ k. 50 Hz  $\pm$  0.1 % in A ,  $\pm$  0.1° in  $\phi$  & BW ~ few kHz ( $\tau_{ren}$  ~ 1 ms) Mechanical tuning: BW ~ 1 Hz (\u03c6<sub>rep</sub> ~ 1 s)

The THOMX RF system is being completed; its integration and commissioning in ThomX is scheduled for 2017. At first, the RF cavity will be RF conditioned up to full power with its final SSPA in the casemate "shielded room" of the new IGLEX research platform located on the Orsay university campus. Then the complete RF system will be implemented and commissioned in the ThomX storage ring.